ELECTRICAL ENGINEERING

PAPER-I

Time Allowed: **Three Hours**

Maximum Marks: 300

Question Paper Specific Instructions

Please reach each of the following instruction carefully before attempting questions:

There are **EIGHT** questions divided in **TWO** sections.

Candidate has to attempt **FIVE** questions in all

Questions **No.1** and **5** are **compulsory** and out of the remaining, any **THREE** are to be attempted choosing at least **ONE** question from each section.

The number of marks carried by a question/part is indicated against it.

Answers must be written in the medium authorized in the Admission Certificate which must be stated clearly on the cover of this Question-cum-Answer (QCA) Booklet in the space provided. No marks will be given for answers written in medium other than the authorized one.

Assume suitable data, if considered necessary and indicate the same clearly.

Unless otherwise mentioned, symbols and notations carry their usual standard meanings.

Attempts of questions shall be counted in sequential order. Unless struck off, attempt of a question shall be counted even if attempted partly. Any page of portion of the page left blank in the Question-cum-Answer Booklet must be clearly struck off.



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1



|EE-IES-2018, PAPER-I|

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The parallel plate capacitor consisting of two dielectric materials is shown in the figure. The middle dielectric slab is placed symmetrically with respect to the plates. If the potential difference between one of the plates and nearest surface of dielectric interface is 4 volts, determine $\frac{\epsilon_1}{\epsilon_2}$. Assume parallel plate capacitor has an electrode area of A m².

[12 Marks]



Write the equation related to the drain current (I_D) and Gate to source voltage V_{gs} explaining all the parameters for

- (i) Depletion type MOSFET
- (ii) Enhancement type MOSFET
- (iii) Determine V_{DS} for the circuit shown in the figure.

[12 Marks]

2.

(a) Show that in the interval (0, 1)

$$\cos \pi x = \frac{8}{\pi} \sum_{n=1}^{\infty} \frac{n}{4n^2 - 1} \cdot \sin 2n\pi x$$

[20 Marks]



[20 Marks]

(b)



Determine the value of the Load Resistance R_L to be connected across terminals X-Y to receive maximum power. Also, obtain the value of this maximum power.



- (i) With bypass capacitor.
- (ii) Without bypass capacitor.
- (iii) Calculate voltage gain in part (i) and part (ii), if $R_1 = 90 \text{ k}\Omega$, $R_2 = 10 \text{ k}\Omega$, $R_E = 0.8 \text{ k}\Omega$, $\beta = 200$, $r_0 = 50 \text{ k}\Omega$, $R_C = 2.2 \text{ k}\Omega$, and $V_{CC} = +15 \text{ V}$.

Compare both voltage gains and write conclusion in short.

[20 Marks]

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[20 Marks]



For the network shown, $v_s = 24\sqrt{2} \sin 100t$, coefficient of coupling $k = \frac{1}{3}$ between two coupled coils.

- (i) Write loop equation in vector-matrix for currents I_1 and I_2 .
- (ii) Obtain the impedance seen by the source v_s and the power factor of the source.

[20 Marks]



- (i) Explain miller effect capacitance in brief.
- (ii) For the given circuit, prove that
 - (A) Miller effect input capacitance

 $C_{M_{i}} = (1 - A_{v})C_{f}$

(B) Miller effect output capacitance

$$C_{M_o} = \left(1 - \frac{1}{A_v}\right)C_f$$

[20 Marks]

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$$f(x) = \frac{5}{3}e^{-5x}u(x) + \beta e^{2x}u(-x)$$

Where β is a constant and u(x) is the unit step function. Calculate:

- (i) The value of β
- (ii) Mean of X
- (iii) Variance of X

(b)



For the two port network shown, the y-parameter matrix is given

- (i) Obtain the input admittance Y_{in} as shown in the figure.
- (ii) Obtain voltage gain $\frac{V_2}{V_2}$

[20 Marks]

[20 Marks]



- (c) (i) State whether the given statement is true or false for practical oscillators with reasons.
 - "Loop gain is generally made slightly larger than unity."
 - (ii) In a general form of oscillator circuit given in figure.



[20 Marks]

SECTION-B

- (a) Mention the type of Bravais space lattice, relationship of crystal axial lengths (x, y, z) and relationship of interaxial angles (α, β, γ) in the following order of the crystal system.
 - (i) Triclinic

5.

- (ii) Monoclinic
- (iii) Orthorhombic and
- (iv) Trigonal

[12 Marks]



6.



- (i) the emf of cell which balanced at 72 cm
- (ii) the percentage error in voltmeter which balances at 64.5 cm when reading 1.33V
- (iii) Percentage error in ammeter that reads 0.43A and balance is obtained at 43.2 cm with Pd across a 2Ω resistor in the ammeter circuit.

[12 Marks]

- (c) (i) Write down algorithm in Pseudocode for sorting an array in descending order. Specify the name of the algorithm you have used.
 - (ii) Write a program segment in any higher level language for Linear search problem. (Specify which language you are using).

[12 Marks]

(d) A non-inductive shunt is used to increase the range of a 10A moving iron ammeter to 100A. The impedance of the instrument including the leads is $(0.06 + j4.71 \times 10^{-3})\Omega$. If the combination is correct on a dc circuit, find the error on ac circuit

[12 Marks]

- (e) (i) Explain the electrochemical breakdown in insulators and discus any two factors that accelerates the breakdown.
 - (ii) A magnetic material having almost a square hysteresis loop has a coercivity of 50 A/m and a remanenence of 0.5T. If this material is used in a toroidal inductor of mean diameter 1.6cm, with a cross-sectional area of 0.25×10^{-4} m², calculate the power loss at a frequency of 50 Hz when the material is driven around one complete hysteresis cycle.

[10 Marks]

- (a) (i) Explain electrical resistivity of metals in terms of thermal and residual components. Also draw the schematic variation of them with respect to temperature.
 - (ii) Writ the relation between magnetic susceptibility and temperature according to Curies Law, Curie-Weiss Law and Neel Law. Sketch the variation of reciprocal of susceptibility with temperature as per the above laws.
 - (iii) What are ferrites? Mention 3 disadvantages. State the reason, why ferrites are suitable for high frequency operation.

[20 Marks]





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- 8. (b) The power consumed by a single phase 11kV load taking 100A at 0.5 power factor lagging is measured on a dynamometer wattmeter used in conjunction with potential transformer (PT) and current transformer (CT). Determines the reading of the wattmeter considering the following data: Nominal ratio of PT and CT are 100: 1 and 20: 1
 Ratio error of PT and CT are +0.8% and -0.2%
 Phase angle errors of PT and CT are +42 minutes and +90 minutes
 Phase angle of the pressure coil due to its inductance is 30 minutes
 - [20 Marks]
 - (c) (i) Is the use of Virtual Memory advisable for Real Time Systems? Justify briefly your answer.
 - (ii) Compare briefly and precisely the LINUX OS with Windows-NT OS.
 - (iii) For File Management how does a DBMS help?

[12 Marks]